

1. Record Nr.	UNINA9910137127303321
Titolo	2016 Compound Semiconductor Week (CSW) [Includes 28th International Conference on Indium Phosphide & Related Materials (IPRM) & 43rd International Symposium on Compound Semiconductors (ISCS)] / / Institute of Electrical and Electronics Engineers
Pubbl/distr/stampa	[Piscataway, New Jersey] : , : IEEE, , 2016
ISBN	1-5090-1964-2
Descrizione fisica	1 online resource (349 pages)
Disciplina	621.38152
Soggetti	Compound semiconductors
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Sommario/riassunto	<p>Annotation CSW 2016 will be the premier forum of 2016 for science, technology and applications of compound semiconductors, addressing the physics, science, and applications of III V and II VI compound semiconductors, SiGe, SiC and related alloys, as well as new materials such as complex oxides and two dimensional materials. Papers are solicited on all compound semiconductor related topics including (IPRM) Epitaxy, novel materials, and nanostructures, Optoelectronics devices and related technologies, Electron devices and related technologies, (ISCS) Growth and related technologies, Photonic devices, Nanocharacterization and nanostructures, Oxide semiconductors, Organic semiconductors and flexible materials, High frequency and high power devices, Physics, spintronics, and novel device concepts, GaN and related semiconductors, Nanocarbon and novel 2D materials.</p>